# MSKSEMI















**ESD** 

TVS

TSS

MOV

GDT

**PLED** 

# Broduct data sheet





SOT-23

#### **Features**

- 340 Watts peak pulse power (tp =  $8/20\mu$ s)
- Bidirectional configurations
- Solid-state silicon-avalanche technology
- Low clamping voltage
- Low leakage current
- Protection two data lines:
- IEC 61000-4-2  $\pm 8kV$  contact  $\pm 15kV$  air
- IEC 61000-4-4 (EFT) 40A (5/50ns)
- IEC 61000-4-5 (Lightning) 12A (8/20μs)

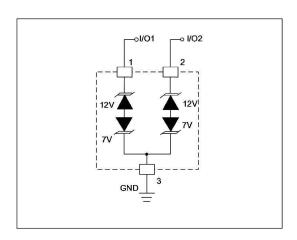
#### **Mechanical Data**

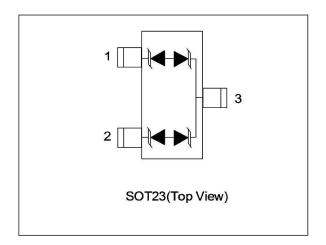
- SOT-23 package
- Molding compound flammability rating: UL 94V-0
- Packaging: Tape and Reel
- RoHS/WEEE Compliant

## **Applications**

- Dataline
- **Automatic Teller Machines**
- Net works
- Power line

# Schematic & PIN Configuration





**Absolute Maximum Rating** 

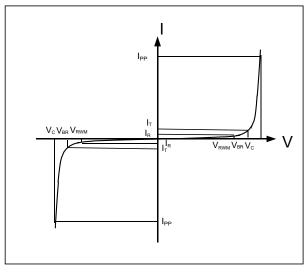
Rating	Symbol	Value	Units
Peak Pulse Power ( t <sub>p</sub> =8/20μs )	P <sub>PP</sub>	340	Watts
Peak Pulse Current ( t <sub>p</sub> =8/20μs ) (note1)	$I_{pp}$	12	A
ESD per IEC 61000-4-2 (Air) ESD per IEC 61000-4-2 (Contact)	$ m V_{ESD}$	15 8	kV
Lead Soldering Temperature	$T_{ m L}$	260(10seconds)	$^{\circ}$
Junction Temperature	TJ	-55 to + 125	$^{\circ}$ C
Storage Temperature	$T_{ m stg}$	-55 to + 125	$^{\circ}$ C

# **Electrical Characteristics**

			Pins 1 to 3 and 2 to 3 (12V TVS)		Pins 3 to 1 and 3 to 2 (7V TVS)				
Parameter	Symbol	Conditions	Min	Typical	Max	Min	Typical	Max	Units
Reverse Stand-Off Voltage	V <sub>RWM</sub>				12			7	V
Reverse Breakdown Voltage	$ m V_{BR}$	IT=1mA	13.3			7.5			V
Reverse Leakage Current	Ir	VR=VRWM			1			1	μΑ
Clamping Voltage	Vc	IPP=12A,tp=8/20μs		28					V
Clamping Voltage	Vc	IPP=20A,tp=8/20μs					20		V
Junction Capacitance	Cj	$V_R = 0V, f = 1MHz$		30			30		pF

# Electrical Parameters (TA = 25°C unless otherwise noted)

Symbol	Parameter	
Ірр	Maximum Reverse Peak Pulse Current	
Vc	Clamping Voltage @ Ipp	
Vrwm	Working Peak Reverse Voltage	
IR	Maximum Reverse Leakage Current @ VRWM	
$V_{\mathrm{BR}}$	Breakdown Voltage @ IT	
Iτ	Test Current	

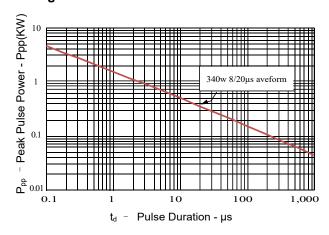


Note: 8/20µs pulse waveform.



# **Typical Characteristics**

Figure 1: Peak Pulse Power vs. Pulse Time



**Figure 2: Power Derating Curve** 

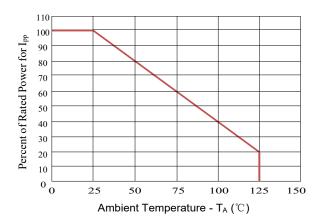


Figure3: Pulse Waveform

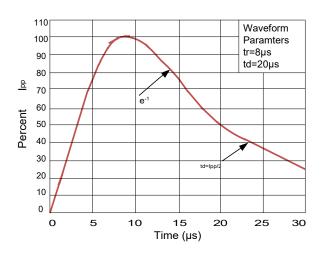
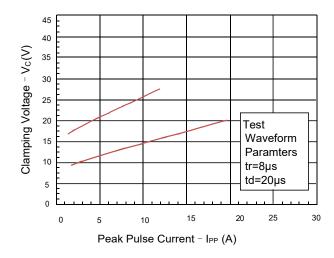
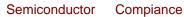


Figure 4: Clamping Voltage vs.lpp



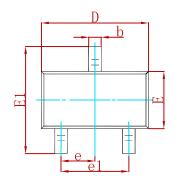


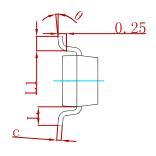


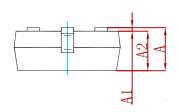




#### **PACKAGE MECHANICAL DATA**

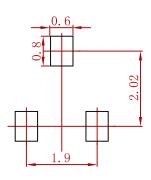






Symbol	Dimensions	In Millimeters	Dimensions In Inches		
Symbol	Min	Max	Min	Max	
Α	0.900	1.150	0.035	0.045	
A1	0.000	0.100	0.000	0.004	
A2	0.900	1.050	0.035	0.041	
b	0.300	0.500	0.012	0.020	
С	0.080	0.150	0.003	0.006	
D	2.800	3.000	0.110	0.118	
Е	1.200	1.400	0.047	0.055	
E1	2.250	2.550	0.089	0.100	
е	0.950 TYP		0.037 TYP		
e1	1.800	2.000	0.071	0.079	
L	0.550 REF		0.022 REF		
L1	0.300	0.500	0.012	0.020	
θ	0°	8°	0°	8°	

# **Suggested Pad Layout**



- 1.Controlling dimension:in millimeters.2.General tolerance:± 0.05mm.3.The pad layout is for reference purposes only.

## **REEL SPECIFICATION**

P/N	PKG	QTY
SM712.TCT	SOT-23	3000



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